

## Two-level system (TLS)

Jukka Pekola<sup>1</sup> and Bayan Karimi<sup>1</sup>

<sup>1</sup>*Pico group, QTF Centre of Excellence, Department of Applied Physics, Aalto University School of Science*

(Dated: February 4, 2021)

### I. SINGLE-ELECTRON BOX (SEB) AS A TWO-LEVEL SYSTEM

Consider SEB as schematically shown in Fig. 1(a). There is an integer number  $n$  of electrons on the island distributed on the capacitors as

$$-ne = C_g(U - V_g) + CU, \quad (1)$$

where  $U = (-ne + C_g V_g)/C_\Sigma$  is the potential of the island and  $V_g$  is the gate voltage. Here  $C_\Sigma = C_g + C$ . The energy of the capacitors in SEB is given by

$$E_{\text{cap}} = \frac{1}{2}C_g(U - V_g)^2 + \frac{1}{2}CU^2 = \frac{(ne)^2}{2C_\Sigma} + \text{const.}, \quad (2)$$

where const. refers to the terms which are not dependent on  $n$ . The free energy of SEB is then

$$E = E_{\text{cap}} - Q_g V_g, \quad (3)$$

where  $Q_g V_g$  is the work done by the voltage source. Since  $Q_g = C_g(V_g - U)$  then by considering only the terms dependent on  $n$  we have

$$E = \frac{(ne)^2}{2C_\Sigma} - \frac{C_g V_g}{C_\Sigma} ne + \text{const.}, \quad (4)$$

or

$$E = E_C(n - n_g)^2, \quad (5)$$

where  $E_C = \frac{e^2}{2C_\Sigma}$  and  $n_g = \frac{C_g V_g}{e}$ . In the gate range  $0 < n_g < 1$ , we may consider SEB as a TLS with

$$\begin{aligned} \Delta E &= E(n=1) - E(n=0) \\ &= E_C(1 - 2n_g). \end{aligned} \quad (6)$$

### II. HEAT, WORK AND INTERNAL ENERGY OF A TWO-LEVEL SYSTEM (TLS)

Heat is associated to transitions in the TLS,  $dQ = dP_1 \Delta E$ , where  $P_1 = \frac{1}{1 + e^{\beta \Delta E}}$  is the population in the excited state. Work corresponds to lifting the level of the excited particles (electrons by the voltage source in a SEB),

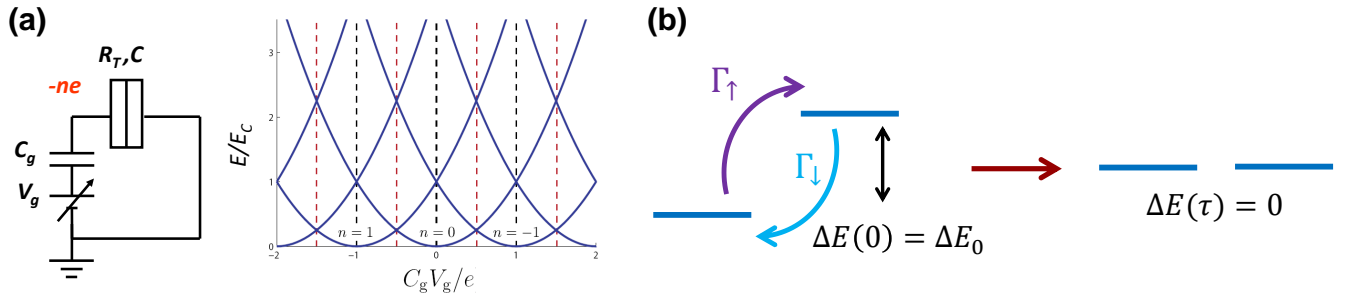


FIG. 1. (a,left) Single-electron box (SEB). (a,right) Energies of different charge states  $n$ . (b) Two-level system moved from finite energy difference initially to degeneracy at time  $\tau$ . In the text the adiabatic ramp is discussed.

$$dW = P_1 d(\Delta E).$$

$$\begin{aligned} dU &= dQ + dW \\ &= dP_1 \Delta E + P_1 d(\Delta E) \\ &= d(P_1 \Delta E). \end{aligned} \tag{7}$$

Thus in going from initial state  $i$  to final state one  $f$ , we have

$$\Delta U = U^{(f)} - U^{(i)} = P_1^{(f)} \Delta E^{(f)} - P_1^{(i)} \Delta E^{(i)}. \tag{8}$$

### III. HEAT AND ENTROPY IN REVERSIBLE DRIVE OF A TLS

We may write  $\dot{Q} = dQ/dt$  as

$$\dot{Q} = \Delta E \dot{P}_1. \tag{9}$$

Then we obtain the total heat from the bath in the process of changing the level spacing from a finite value  $\Delta E_0$  to 0 over time  $\tau$  as

$$\Delta Q = \int_0^\tau dt \Delta E(t) \dot{P}_1(t) = - \int_0^\tau dt \frac{d\Delta E(t)}{dt} P_1(t), \tag{10}$$

where the second step is obtained by partial integration and by observing that the boundary term vanishes when  $\beta \Delta E_0 \gg 1$ .

Assuming linear change  $\frac{d\Delta E(t)}{dt} = -\Delta E_0/\tau$  and quasistatic (reversible) ramp where  $P_1(t) = 1/(1 + e^{\beta \Delta E(t)})$ , we obtain the heat from the bath in this process as

$$\Delta Q^{(0)} = \frac{\Delta E_0}{\tau} \int_0^\tau dt \frac{1}{1 + e^{\beta \Delta E(t)}}. \tag{11}$$

Letting  $\beta \Delta E_0 \rightarrow \infty$ , we have (with  $\beta = 1/(k_B T)$ )

$$\Delta Q^{(0)} = k_B T \ln 2. \tag{12}$$

This corresponds to entropy production  $\Delta S = \Delta Q^{(0)}/T$  of

$$\Delta S = k_B \ln 2 \tag{13}$$

in the TLS.